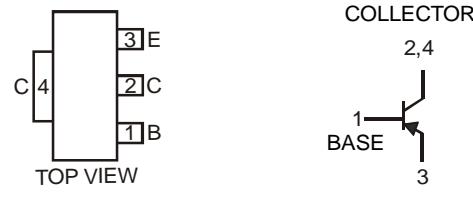
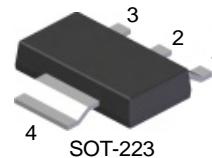


Features

- Epitaxial Planar Die Construction
- Complementary NPN Type Available (DZTA42)
- Ideally Suited for Automated Assembly Processes
- Ideal for Medium Power Switching or Amplification Applications
- Lead Free By Design/RoHS Compliant (Note 1)**
- "Green" Device (Note 2)**



Schematic and Pin Configuration

Mechanical Data

- Case: SOT-223
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Finish - Matte Tin annealed over Copper Leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208
- Marking & Type Code Information: See Page 3
- Ordering Information: See Page 3
- Weight: 0.115 grams (approximate)

Maximum Ratings

$\text{@ } T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	-300	V
Collector-Emitter Voltage	V_{CEO}	-300	V
Emitter-Base Voltage	V_{EBO}	-5	V
Base Current	I_B	-100	mA
Continuous Collector Current	I_C	-500	mA

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation @ $T_A = 25^\circ\text{C}$ (Note 3)	P_d	1	W
Thermal Resistance, Junction to Ambient @ $T_A = 25^\circ\text{C}$ (Note 3)	$R_{\theta JA}$	125	°C/W
Operating and Storage Temperature Range	T_j, T_{STG}	-55 to +150	°C

Electrical Characteristics

$\text{@ } T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Test Conditions
OFF CHARACTERISTICS (Note 4)						
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	-300	—	—	V	$I_C = -100\mu\text{A}, I_E = 0$
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	-300	—	—	V	$I_C = -1\text{mA}, I_B = 0$
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	-5	—	—	V	$I_E = -100\mu\text{A}, I_C = 0$
Collector-Base Cut-Off Current	I_{CBO}	—	—	-0.25	μA	$V_{CB} = -200\text{V}, I_E = 0$
Emitter-Base Cut-Off Current	I_{EBO}	—	—	-0.1	μA	$V_{EB} = -3\text{V}, I_C = 0$
ON CHARACTERISTICS (Note 4)						
Collector-Emitter Saturation Voltage	$V_{CE(\text{SAT})}$	—	—	-0.5	V	$I_C = -20\text{mA}, I_B = -2\text{mA}$
Base-Emitter Saturation Voltage	$V_{BE(\text{SAT})}$	—	—	-0.9	V	$I_C = -20\text{mA}, I_B = -2\text{mA}$
DC Current Gain	h_{FE}	25	—	—	V	$I_C = -1\text{mA}, V_{CE} = -10\text{V}$
		40	—	—		$I_C = -10\text{mA}, V_{CE} = -10\text{V}$
		25	—	—		$I_C = -30\text{mA}, V_{CE} = -10\text{V}$
SMALL SIGNAL CHARACTERISTICS						
Gain-Bandwidth Product	f_T	50	—	—	MHz	$I_C = -10\text{mA}, V_{CE} = -20\text{V}, f = 100\text{MHz}$
Output Capacitance	C_{obo}	—	—	6	pF	$V_{CB} = -20\text{V}, f = 1\text{MHz}$

Notes:

- No purposefully added lead.
- Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
- Device mounted on FR-4 PCB, 1" x 0.85" x 0.052"; pad layout as shown on page 4 or on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at <http://www.diodes.com/datasheets/ap02001.pdf>.
- Measured under pulsed conditions. Pulse Test: Pulse width, $tp < 300\text{ }\mu\text{s}$, Duty Cycle, $d < 2\%$

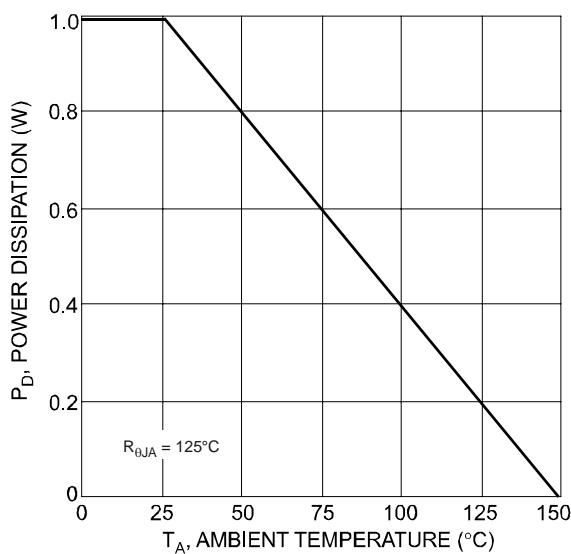


Fig. 1, Power Dissipation vs. Ambient Temperature (Note 3)

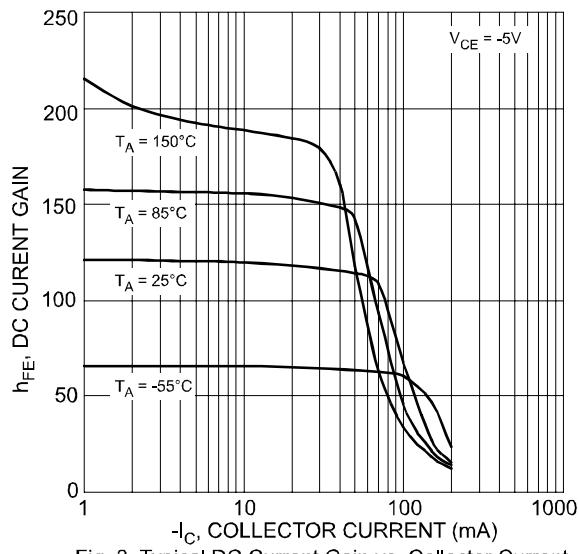


Fig. 3, Typical DC Current Gain vs. Collector Current

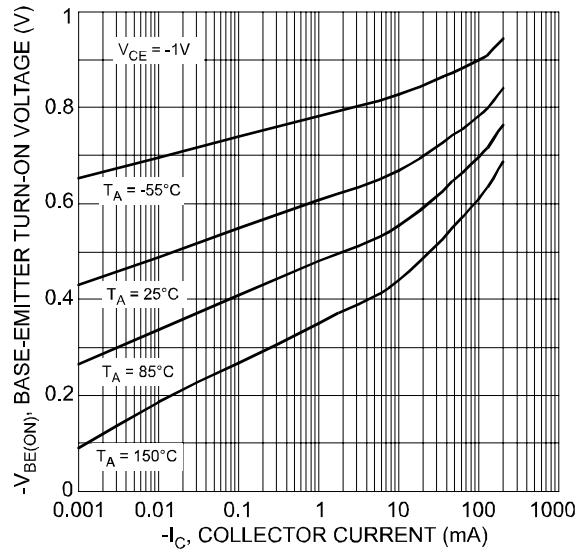


Fig. 5, Typical Base-Emitter Turn-On Voltage vs. Collector Current

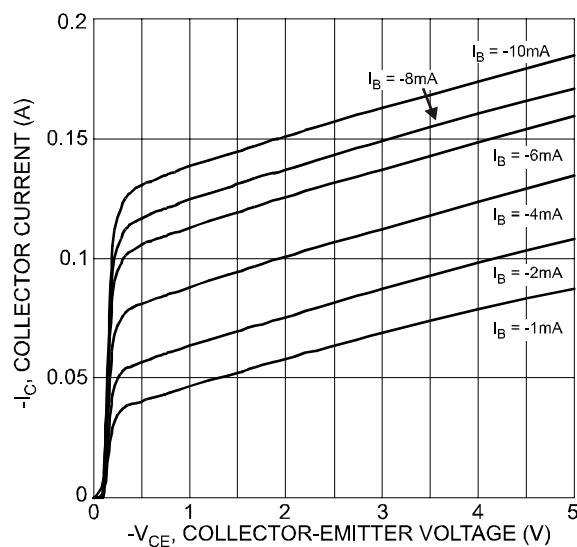


Fig. 2, Typical Collector Current vs. Collector-Emitter Voltage

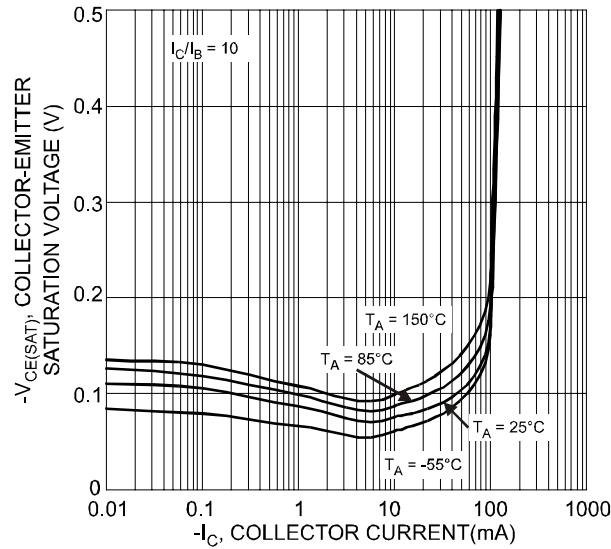


Fig. 4, Typical Collector-Emitter Saturation Voltage vs. Collector Current

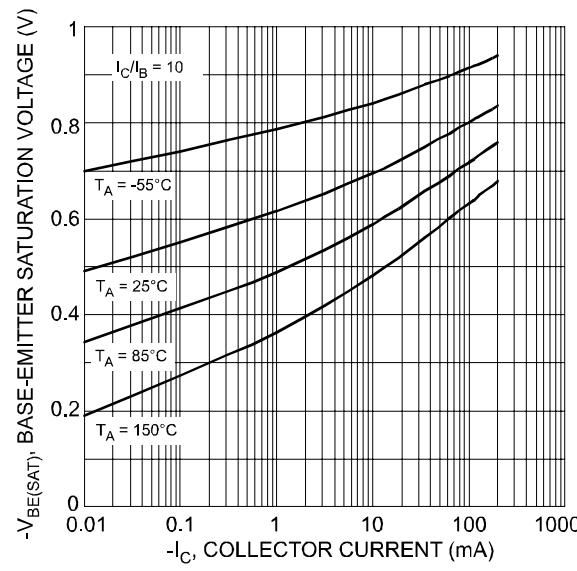


Fig. 6, Typical Base-Emitter Saturation Voltage vs. Collector Current

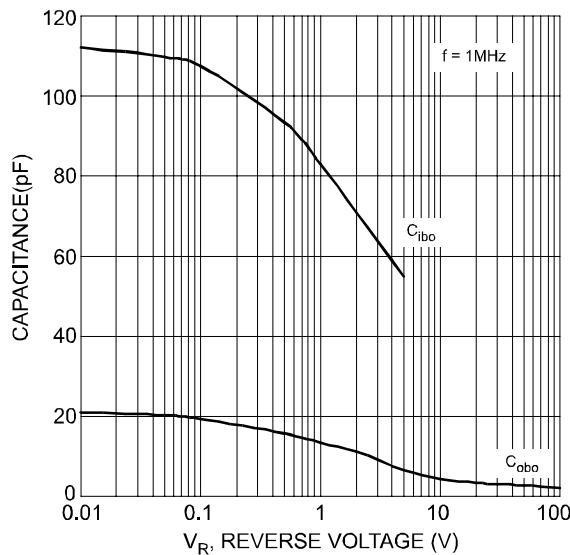


Fig. 7, Typical Capacitance Characteristics

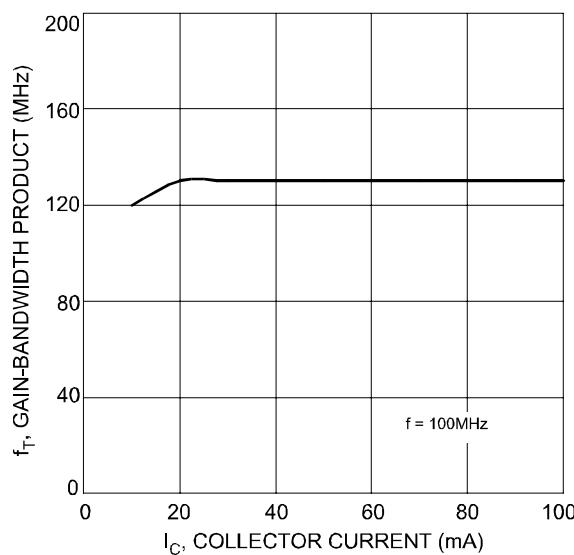


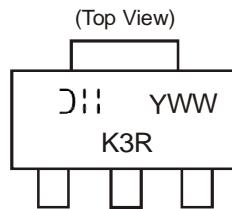
Fig. 8, Typical Gain-Bandwidth Product vs. Collector Current

Ordering Information (Note 5)

Device	Packaging	Shipping
DZTA92-13	SOT-223	2500/Tape & Reel

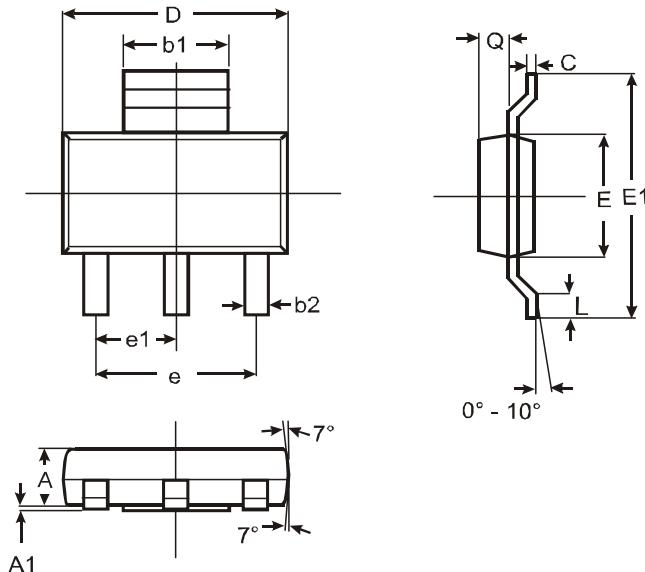
Notes: 5. For packaging details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

Marking Information



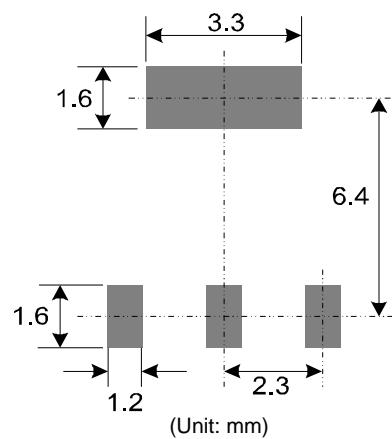
K3R = Product Type Marking Code
 YWW = Date Code Marking
 Y = Last digit of year ex: 7 = 2007
 WW = Week code 01 - 52

Package Outline Dimensions



SOT-223			
Dim	Min	Max	Typ
A	1.55	1.65	1.60
A1	0.010	0.15	0.05
b1	2.90	3.10	3.00
b2	0.60	0.80	0.70
C	0.20	0.30	0.25
D	6.45	6.55	6.50
E	3.45	3.55	3.50
E1	6.90	7.10	7.00
e	—	—	4.60
e1	—	—	2.30
L	0.55	0.75	0.65
Q	0.84	0.94	0.89

All Dimensions in mm

Suggested Pad Layout: (Based on IPC-SM-782)**IMPORTANT NOTICE**

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